BLF184XR; BLF184XRS

Power LDMOS transistor Rev. 4 — 1 September 2015

AMPLEON

Product data sheet

Product profile 1.

1.1 General description

A 700 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 600 MHz band.

Table 1. **Application information**

Test signal	f	V _{DS}	PL	Gp	η_D
	(MHz)	(V)	(W)	(dB)	(%)
pulsed RF	108	50	700	23.9	73.5
CW	108	50	750	23.5	81.9

1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 600 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified ou	ıtline Graphic symbol
BLF184)	KR (SOT1214A)		
1	drain1		
2	drain2	1 2	
3	gate1		J ₅ S • •
4	gate2	3 4	3——5
5	source	[1]	4
			'
			2 sym117
BLF184X	KRS (SOT1214B)		
1	drain1		_
2	drain2	1 2	1
3	gate1		J
4	gate2	3 4	5 3 - 5
5	source	[1]	4
			'⊢¬
			2 sym117
			·

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Name Description		
BLF184XR	-	flanged ceramic package; 2 mounting holes; 4 leads	SOT1214A	
BLF184XRS	-	earless flanged ceramic package; 4 leads	SOT1214B	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	135	V
V_{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

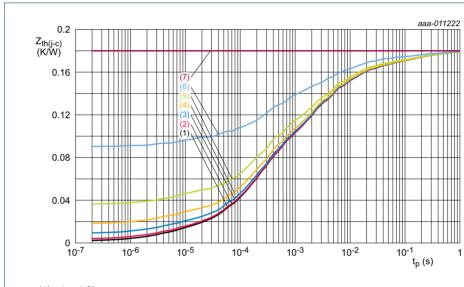
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5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T _j = 150 °C	[1][2]	0.18	K/W
Z _{th(j-c)}	transient thermal impedance from junction to case	T_j = 150 °C; t_p = 100 μs; δ = 20 %	[3]	0.065	K/W

- [1] T_i is the junction temperature.
- [2] $R_{th(j-c)}$ is measured under RF conditions.
- [3] See Figure 3.



- (1) $\delta = 1 \%$
- (2) $\delta = 2 \%$
- (3) $\delta = 5 \%$
- (4) $\delta = 10 \%$
- (5) $\delta = 20 \%$
- (6) $\delta = 50 \%$
- (7) $\delta = 100 \% (DC)$

Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

6. Characteristics

Table 6. DC characteristics

 $T_j = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.75 \text{ mA}$	135	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 275 \text{ mA}$	1.25	1.9	2.25	٧
V_{GSq}	gate-source quiescent voltage	$V_{DS} = 50 \text{ V}; I_{D} = 50 \text{ mA}$	-	1.6	-	V

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Table 6. DC characteristics ...continued

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	38.5	-	A
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 9.625 A$	-	0.16	-	Ω

Table 7. AC characteristics

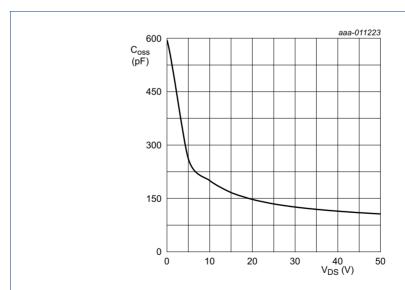
 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	3.1	-	pF
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	292	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	107	-	pF

Table 8. RF characteristics

Test signal: pulsed RF; t_p = 100 μ s; δ = 20 %; f = 108 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 100 mA; T_{case} = 25 $^{\circ}$ C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G_p	power gain	P _L = 700 W	22.8	23.9	-	dB
RLin	input return loss	P _L = 700 W	-	-20	-13	dB
η_{D}	drain efficiency	P _L = 700 W	71	73.5	-	%



 $V_{GS} = 0 V$; f = 1 MHz.

Fig 2. Output capacitance as a function of drain-source voltage; typical values per section

7. Test information

7.1 Ruggedness in class-AB operation

The BLF184XR and BLF184XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; $I_{Dq} = 100 \text{ mA}$; $P_L = 700 \text{ W}$ pulsed; f = 108 MHz.

7.2 Impedance information

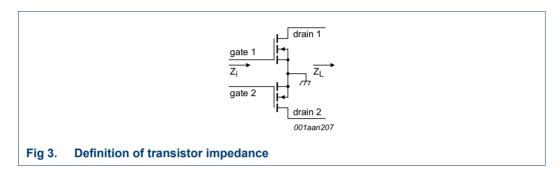


Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at V_{DS} = 50 V and P_L = 700 W.

f	Z _i	Z _L
(MHz)	(Ω)	(Ω)
108	5.8 – j19.1	5.5 + j1.0

7.3 UIS avalanche energy

Table 10. Typical avalanche data per section

 T_{amb} = 25 °C; typical test data; test jig without water cooling.

las	E _{AS}
(A)	(J)
	4.3
20	2.1
25	1.3

For information see application note AN10273.

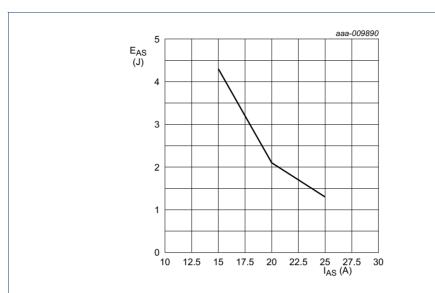


Fig 4. Non-repetitive avalanche energy as a function of single pulse avalanche current, typical values

7.4 Test circuit

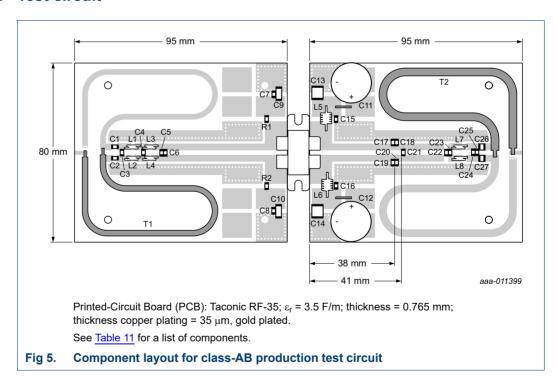


Table 11. List of components

For test circuit see Figure 5.

Component	Description	Value	Remarks
C1, C2	multilayer ceramic chip capacitor	910 pF [1]	
C3	multilayer ceramic chip capacitor	47 pF [1]	
C4	multilayer ceramic chip capacitor	51 pF [1]	

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Table 11. List of components ...continued For test circuit see <u>Figure 5</u>.

Component	Description	Value	Remarks
C5	multilayer ceramic chip capacitor	100 pF [1]	
C6, C23	multilayer ceramic chip capacitor	20 pF	
C7, C8, C15, C16	multilayer ceramic chip capacitor	820 pF [1]	
C9, C10, C13, C14	multilayer ceramic chip capacitor	4.7 μF, 100 V	TDK C5750X7R2A475KT
C11, C12	electrolytic capacitor	1000 μF, 63 V	
C17, C19	multilayer ceramic chip capacitor	39 pF [1]	
C18, C20	multilayer ceramic chip capacitor	27 pF [1]	
C21	multilayer ceramic chip capacitor	7.5 pF [1]	
C22	multilayer ceramic chip capacitor	22 pF [1]	
C24, C25	multilayer ceramic chip capacitor	27 pF [1]	
C26, C27	multilayer ceramic chip capacitor	1 nF [2]	
L1, L2, L3, L4	1.5 turn 0.8 mm copper wire	D = 2.8 mm	
L5, L6	5.5 turn 0.8 mm copper wire	D = 3.6 mm	
L7, L8	1 turn 1.5 mm copper wire	D = 4 mm	
R1, R2	resistor	10 Ω	SMD 1206
T1	semi rigid coax	25 Ω, length = 160 mm	Micro-Coax UT-090C-25
T2	semi rigid coax	25 Ω , length = 160 mm	Micro-Coax UT-141C-25

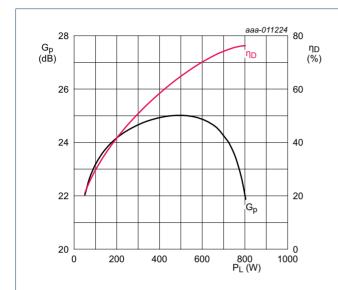
^[1] American Technical Ceramics type 800B or capacitor of same quality.

^[2] American Technical Ceramics type 100B or capacitor of same quality.

7.5 Graphical data

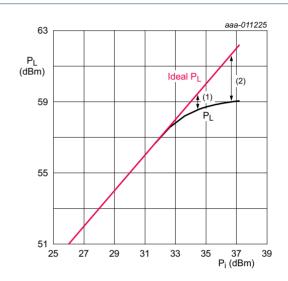
The following figures are measured in a class-AB production test circuit.

7.5.1 1-Tone CW pulsed



 V_{DS} = 50 V; I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

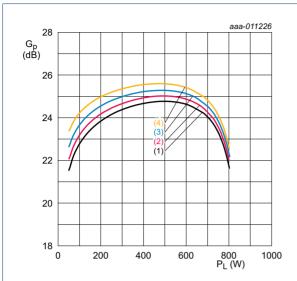
Fig 6. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 50 V; I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 $\mu s;$ δ = 20 %.

- (1) $P_{L(1dB)} = 58.6 \text{ dBm} (720 \text{ W})$
- (2) $P_{L(3dB)} = 59 \text{ dBm } (800 \text{ W})$

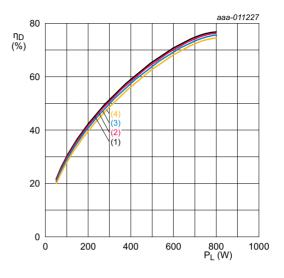
Fig 7. Output power as a function of input power; typical values



 V_{DS} = 50 V; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$

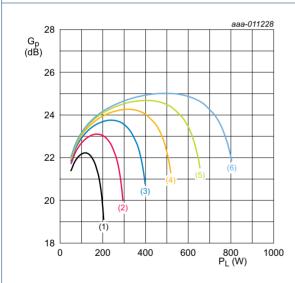
Fig 8. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}$; f = 108 MHz; $t_p = 100 \text{ } \mu\text{s}$; $\delta = 20 \text{ } \%$.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 100 \text{ mA}$

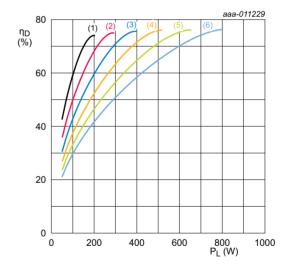
Fig 9. Drain efficiency as a function of output power; typical values



 I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $V_{DS} = 25 \text{ V}$
- (2) $V_{DS} = 30 \text{ V}$
- (3) $V_{DS} = 35 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$
- (5) $V_{DS} = 45 \text{ V}$
- (6) $V_{DS} = 50 \text{ V}$

Fig 10. Power gain as a function of output power; typical values



 I_{Dq} = 100 mA; f = 108 MHz; t_p = 100 $\mu s; \, \delta$ = 20 %.

- (1) $V_{DS} = 25 \text{ V}$
- (2) $V_{DS} = 30 \text{ V}$
- (3) $V_{DS} = 35 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$
- (5) $V_{DS} = 45 V$
- (6) $V_{DS} = 50 \text{ V}$

Fig 11. Drain efficiency as a function of output power; typical values

8. Package outline

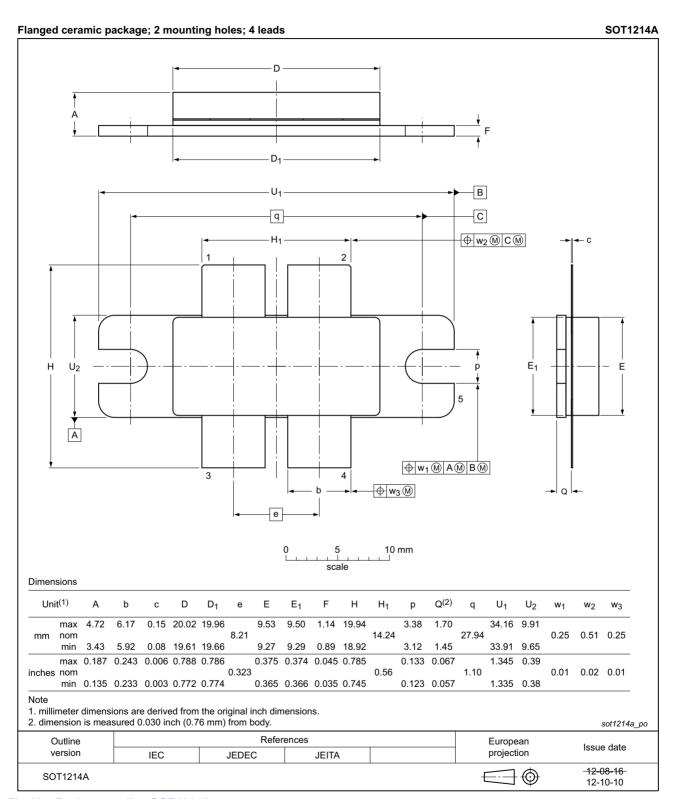


Fig 12. Package outline SOT1214A

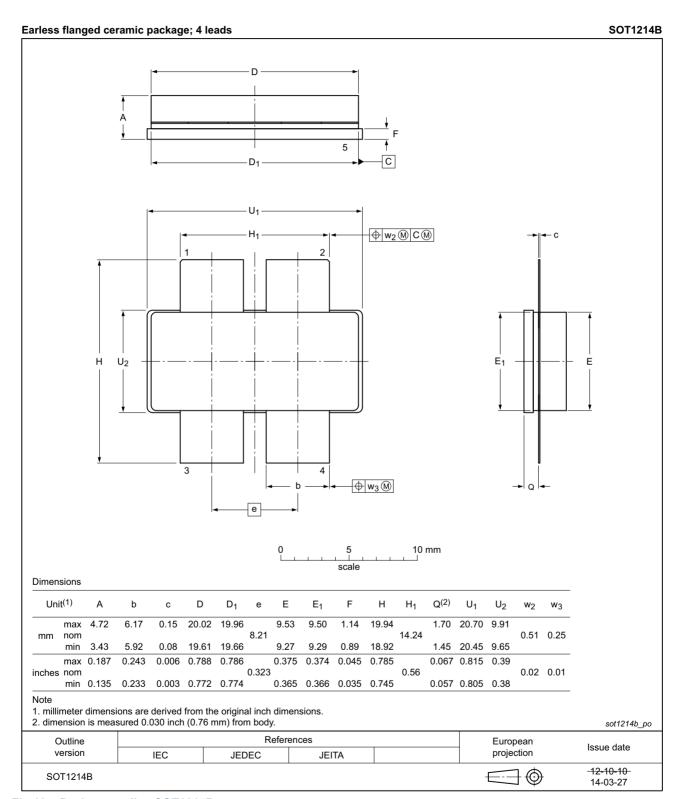


Fig 13. Package outline SOT1214B

Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 12. Abbreviations

Acronym	Description			
CW	Continuous Wave			
ESD	ElectroStatic Discharge			
HF	High Frequency			
LDMOS	Laterally Diffused Metal-Oxide Semiconductor			
MTF	Median Time to Failure			
SMD	Surface Mounted Device			
UIS	Unclamped Inductive Switching			
VSWR	Voltage Standing-Wave Ratio			

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF184XR_BLF184XRS v.4	20150901	Product data sheet	-	BLF184XR_BLF184XRS v.3
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLF184XR_BLF184XRS v.3	20140401	Product data sheet	-	BLF184XR_BLF184XRS v.2
BLF184XR_BLF184XRS v.2	20140227	Preliminary data sheet	-	BLF184XR_BLF184XRS v.1
BLF184XR_BLF184XRS v.1	20130506	Objective data sheet	-	-

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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